

INA188

Technical [Documents](http://www.ti.com/product/INA188?dcmp=dsproject&hqs=td&#doctype2)

Precision, Zero-Drift, Rail-to-Rail Out, High-Voltage Instrumentation Amplifier

1 Features

- Excellent DC Performance:
	- Low Input Offset Voltage: 55 μV (max)

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[Sample &](http://www.ti.com/product/INA188?dcmp=dsproject&hqs=sandbuy&#samplebuy) $\frac{1}{2}$ Buy

- Low Input Offset Drift: 0.2 μV/°C (max)
- High CMRR: 104 dB, $G \ge 10$ (min)
- Low Input Noise:
	- 12 nV/ \sqrt{Hz} at 1 kHz
	- 0.25 μV_{PP} (0.1 Hz to 10 Hz)
- Wide Supply Range:
	- Single Supply: 4 V to 36 V
	- $-$ Dual Supply: ± 2 V to ± 18 V
- Gain Set with a Single External Resistor:
	- Gain Equation: G = 1 + (50 kΩ / R_G)
	- Gain Error: 0.007%, G = 1
	- $-$ Gain Drift: 5 ppm/ \degree C (max) G = 1
- Input Voltage: $(V-) + 0.1 V$ to $(V+) 1.5 V$
- RFI-Filtered Inputs
- Rail-to-Rail Output
- Low Quiescent Current: 1.4 mA
- Operating Temperature: –55°C to +150°C
- SOIC-8 and DFN-8 Packages

2 Applications

- **Bridge Amplifiers**
- **ECG Amplifiers**
- Pressure Sensors
- **Medical Instrumentation**
- Portable Instrumentation
- Weigh Scales
- Thermocouple Amplifiers
- RTD Sensor Amplifiers
- Data Acquisition

3 Description

Tools & [Software](http://www.ti.com/product/INA188?dcmp=dsproject&hqs=sw&#desKit)

The INA188 is a precision instrumentation amplifier that uses TI proprietary auto-zeroing techniques to achieve low offset voltage, near-zero offset and gain drift, excellent linearity, and exceptionally low-noise density (12 nV/√Hz) that extends down to dc.

Support & **[Community](http://www.ti.com/product/INA188?dcmp=dsproject&hqs=support&#community)**

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The INA188 is optimized to provide excellent common-mode rejection of greater than 104 dB (G \geq 10). Superior common-mode and supply rejection supports high-resolution, precise measurement applications. The versatile three op-amp design offers a rail-to-rail output, low-voltage operation from a 4-V single supply as well as dual supplies up to $±18$ V, and a wide, high-impedance input range. These specifications make this device ideal for universal signal measurement and sensor conditioning (such as temperature or bridge applications).

A single external resistor sets any gain from 1 to 1000. The INA188 is designed to use an industrystandard gain equation: G = 1 + (50 k Ω / R_G). The reference pin can be used for level-shifting in singlesupply operation or for an offset calibration.

The INA188 is specified over the temperature range of –40°C to +125°C .

Device Information

- (1) For all available packages, see the orderable addendum at the end of the data sheet.
- (2) The DRJ package (WSON-8) is a preview device.

Simplified Schematic

Texas
Instruments

Table of Contents

4 Revision History

5 Pin Configuration and Functions

Pin Functions

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) $⁽¹⁾$ </sup>

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) Input pins are diode-clamped to the power-supply rails. Input signals that can swing more than 0.3 V beyond the supply rails must be current limited to 10 mA or less.

(3) Short-circuit to ground.

6.2 ESD Ratings

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

6.4 Thermal Information

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](http://www.ti.com/lit/pdf/spra953).

6.5 **Electrical Characteristics:** $V_s = \pm 4$ V to ± 18 V ($V_s = 8$ V to 36 V)

 $RTI = Referred-to-input.$

(1) Total V_{OS} , referred-to-input = (V_{OS1}) + (V_{OSO} / G).

(2) RTI = Referred-to-input.

(3) 300-hour life test at 150°C demonstrated a randor (3) 300-hour life test at 150°C demonstrated a randomly distributed variation of approximately 1 μV.

 (4) Does not include effects of external resistor R_G.

RUMENTS

EXAS

Electrical Characteristics: $V_s = \pm 4$ V to ± 18 V ($V_s = 8$ V to 36 V) (continued)

At $T_A = 25^{\circ}$ C, $R_L = 10$ k Ω , $V_{REF} = V_S / 2$, and $G = 1$, unless otherwise noted.

(5) See *Typical Characteristics* curves, *Output Voltage Swing vs Output Current* [\(Figure](#page-11-0) 19 to [Figure](#page-11-1) 22).

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6.6 Electrical Characteristics: $V_s = \pm 2$ V to $\lt \pm 4$ V ($V_s = 4$ V to $\lt 8$ V)

At T_A = 25°C, R_L = 10 kΩ, V_{REF} = V_S / 2, and G = 1, unless otherwise noted. Specifications not shown are identical to the *Electrical Characteristics* table for $V_S = \pm 2 \text{ V}$ to $\pm 18 \text{ V}$ ($V_S = 8 \text{ V}$ to 36 V).

(1) Total V_{OS} , referred-to-input = $(V_{OSI}) + (V_{OSO} / G)$.

 (2) RTI = Referred-to-input.
(3) 300-hour life test at 150° (3) 300-hour life test at 150°C demonstrated randomly distributed variation of approximately 1 μV.

 (4) Does not include effects of external resistor R_G.

EXAS STRUMENTS

Electrical Characteristics: $V_s = \pm 2$ V to < ± 4 V (V_s = 4 V to < 8 V) (continued)

At T_A = 25°C, R_L = 10 kΩ, V_{REF} = V_S / 2, and G = 1, unless otherwise noted. Specifications not shown are identical to the *Electrical Characteristics* table for $V_S = \pm 2$ V to ± 18 V ($V_S = 8$ V to 36 V).

(5) See *Typical Characteristics* curves, *Output Voltage Swing vs Output Current* [\(Figure](#page-11-0) 19 to [Figure](#page-11-1) 22).

6.7 Typical Characteristics

At $T_A = 25^{\circ}$ C, $V_S = \pm 15$ V, R_L = 10 kΩ, V_{REF} = midsupply, and G = 1, unless otherwise noted.

[INA188](http://www.ti.com/product/ina188?qgpn=ina188) SBOS632 –SEPTEMBER 2015 **www.ti.com**

STRUMENTS

EXAS

Typical Characteristics (continued)

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NSTRUMENTS

Texas

Typical Characteristics (continued)

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NSTRUMENTS

EXAS

Typical Characteristics (continued)

7 Detailed Description

7.1 Overview

The INA188 is a monolithic instrumentation amplifier (INA) based on the 36-V, precision zero-drift [OPA188](http://www.ti.com/product/OPA188) (operational amplifier) core. The INA188 also integrates laser-trimmed resistors to ensure excellent commonmode rejection and low gain error. The combination of the zero-drift amplifier core and the precision resistors allows this device to achieve outstanding dc precision and makes the INA188 ideal for many high-voltage industrial applications.

7.2 Functional Block Diagram

7.3 Feature Description

7.3.1 Inside the INA188

The *[Functional](#page-16-2) Block Diagram* section provides a detailed diagram for the INA188, including the ESD protection and radio frequency interference (RFI) filtering. Instrumentation amplifiers are commonly represented in a simplified form, as shown in [Figure](#page-17-1) 47.

Figure 47. INA Simplified Form

A brief description of the internal operation is as follows:

The differential input voltage applied across R_G causes a signal current to flow through the R_G resistor and both R_F resistors. The output difference amplifier (A₃) removes the common-mode component of the input signal and refers the output signal to the REF pin.

The equations shown in the *[Functional](#page-16-2) Block Diagram* section describe the output voltages of A₁ and A₂. Understanding the internal node voltages is useful to avoid saturating the device and to ensure proper device operation.

7.3.2 Setting the Gain

The gain of the INA188 is set by a single external resistor, R_G , connected between pins 1 and 8. The value of R_G is selected according to [Equation](#page-17-2) 1:

$$
G = 1 + \frac{50 \text{ k}\Omega}{R_G} \tag{1}
$$

[Table](#page-17-3) 1 lists several commonly-used gains and resistor values. The 50-kΩ term in [Equation](#page-17-2) 1 comes from the sum of the two internal 25-kΩ feedback resistors. These on-chip resistors are laser-trimmed to accurate absolute values. The accuracy and temperature coefficients of these resistors are included in the gain accuracy and drift specifications of the INA188.

(1) NC denotes no connection. When using the SPICE model, the simulation does not converge unless a resistor is connected to the R_G pins; use a very large resistor value.

The stability and temperature drift of the external gain setting resistor, R_G , also affects gain. The contribution of R_G to gain accuracy and drift can be determined from [Equation](#page-17-2) 1.

The best gain drift of 5 ppm/°C can be achieved when the INA188 uses G = 1 without R_G connected. In this case, gain drift is limited only by the slight mismatch of the temperature coefficient of the integrated 20-kΩ resistors in the differential amplifier (A₃). At gains greater than 1, gain drift increases as a result of the individual drift of the 25-kΩ resistors in the feedback of A₁ and A₂, relative to the drift of the external gain resistor R_G. The low temperature coefficient of the internal feedback resistors significantly improves the overall temperature stability of applications using gains greater than 1 V/V over competing alternate solutions.

Low resistor values required for high gain can make wiring resistance important. Sockets add to the wiring resistance and contribute additional gain error (such as a possible unstable gain error) at gains of approximately 100 or greater. To ensure stability, avoid parasitic capacitance of more than a few picofarads at R_G connections. Careful matching of any parasitics on both R^G pins maintains optimal CMRR over frequency; see *Typical Characteristics* curve, [Figure](#page-10-0) 17.

7.3.3 Zero Drift Topology

7.3.3.1 Internal Offset Correction

[Figure](#page-18-0) 48 shows a simple representation of the proprietary zero-drift architecture for one of the three amplifiers that comprise the INA188. These high-precision input amplifiers enable very low dc error and drift as a result of a modern chopper technology with an embedded synchronous filter that removes nearly all chopping noise. The chopping frequency is approximately 750 kHz. This amplifier is zero-corrected every 3 μs using a proprietary technique. This design has no aliasing.

Figure 48. Zero-Drift Amplifier Functional Block Diagram

7.3.3.2 Noise Performance

This zero-drift architecture reduces flicker (1/f) noise to a minimum, and therefore enables the precise measurement of small dc-signals with high resolution, accuracy, and repeatability. The auto-calibration technique used by the INA188 results in reduced low-frequency noise, typically only 12 nV/√Hz (at G = 100). The spectral noise density is detailed in [Figure](#page-23-0) 53. Low-frequency noise of the INA188 is approximately 0.25 μV_{PP} measured from 0.1 Hz to 10 Hz (at $G = 100$).

7.3.3.3 Input Bias Current Clock Feedthrough

Zero-drift amplifiers, such as the INA188, use switching on their inputs to correct for the intrinsic offset and drift of the amplifier. Charge injection from the integrated switches on the inputs can introduce very short transients in the input bias current of the amplifier. The extremely short duration of these pulses prevents them from being amplified; however, the pulses can be coupled to the output of the amplifier through the feedback network. The most effective method to prevent transients in the input bias current from producing additional noise at the amplifier output is to use a low-pass filter (such as an RC network).

7.3.4 EMI Rejection

The INA188 uses integrated electromagnetic interference (EMI) filtering to reduce the effects of EMI from sources (such as wireless communications) and densely-populated boards with a mix of analog signal-chain and digital components. The INA188 is specifically designed to minimize susceptibility to EMI by incorporating an internal low-pass filter. Depending on the end-system requirements, additional EMI filters may be required near the signal inputs of the system, as well as incorporating known good practices such as using short traces, lowpass filters, and damping resistors combined with parallel and shielded signal routing. Texas Instruments developed a method to accurately measure the immunity of an amplifier over a broad frequency spectrum, extending from 10 MHz to 6 GHz. This method uses an EMI rejection ratio (EMIRR) to quantify the INA188 ability to reject EMI. [Figure](#page-19-0) 49 and [Figure](#page-19-0) 50 show the INA188 EMIRR graph for both differential and common-mode EMI rejection across this frequency range. [Table](#page-19-1) 2 shows the EMIRR values for the INA188 at frequencies commonly encountered in real-world applications. Applications listed in [Table](#page-19-1) 2 can be centered on or operated near the particular frequency shown.

Table 2. INA188 EMIRR for Frequencies of Interest

7.3.5 Input Protection and Electrical Overstress

Designers often ask questions about the capability of an amplifier to withstand electrical overstress. These questions tend to focus on the device inputs, but can involve the supply voltage pins or even the output pin. Each of these different pin functions have electrical stress limits determined by the voltage breakdown characteristics of the particular semiconductor fabrication process and specific circuits connected to the pin. Additionally, internal ESD protection is built into these circuits to protect them from accidental ESD events both before and during product assembly.

Having a good understanding of this basic ESD circuitry and its relevance to an electrical overstress event is helpful. The *[Functional](#page-16-2) Block Diagram* section illustrates the ESD circuits contained in the INA188. The ESD protection circuitry involves several current-steering diodes connected from the input and output pins and routed back to the internal power-supply lines. This protection circuitry is intended to remain inactive during normal circuit operation.

The input pins of the INA188 are protected with internal diodes connected to the power-supply rails. These diodes clamp the applied signal to prevent the input circuitry from being damaged. If the input signal voltage can exceed the power supplies by more than 0.3 V, limit the input signal current to less than 10 mA to protect the internal clamp diodes. This current limiting can generally be done with a series input resistor. Some signal sources are inherently current-limited and do not require limiting resistors.

7.3.6 Input Common-Mode Range

The linear input voltage range of the INA188 input circuitry extends from 100 mV inside the negative supply voltage to 1.5 V below the positive supply, and maintains 84-dB (minimum) common-mode rejection throughout this range. The common-mode range for most common operating conditions is best calculated using the [INA](http://www.ti.com/tool/ina-cmv-calc) [common-mode](http://www.ti.com/tool/ina-cmv-calc) range calculating tool. The INA188 can operate over a wide range of power supplies and V_{REF} configurations, thus providing a comprehensive guide to common-mode range limits for all possible conditions is impractical.

The most commonly overlooked overload condition occurs when a circuit exceeds the output swing of A_1 and A_2 , which are internal circuit nodes that cannot be measured. Calculating the expected voltages at the output of A_1 and A² (see the *[Functional](#page-16-2) Block Diagram* section) provides a check for the most common overload conditions. The designs of A_1 and A_2 are identical and the outputs can swing to within approximately 250 mV of the powersupply rails. For example, when the A_2 output is saturated, A_1 can continue to be in linear operation, responding to changes in the noninverting input voltage. This difference can give the appearance of linear operation but the output voltage is invalid.

7.4 Device Functional Modes

7.4.1 Single-Supply Operation

The INA188 can be used on single power supplies of 4 V to 36 V. Use the output REF pin to level shift the internal output voltage into a linear operating condition. Ideally, connecting the REF pin to a potential that is midsupply avoids saturating the output of the input amplifiers (A_1 and A_2). Actual output voltage swing is limited to 250 mV above ground when the load is referred to ground. The typical characteristic curves, *Output Voltage Swing vs Output Current* ([Figure](#page-11-0) 19 to [Figure](#page-11-1) 22) illustrates how the output voltage swing varies with output current. See the *Driving the [Reference](#page-23-1) Pin* section for information on how to adequately drive the reference pin.

With single-supply operation, V_{IN+} and V_{IN-} must both be 0.1 V above ground for linear operation. For instance, the inverting input cannot be connected to ground to measure a voltage connected to the noninverting input.

7.4.2 Offset Trimming

Most applications require no external offset adjustment; however, if necessary, adjustments can be made by applying a voltage to the REF pin. [Figure](#page-21-0) 51 shows an optional circuit for trimming the output offset voltage. The voltage applied to the REF pin is summed at the output. The op amp buffer provides low impedance at the REF pin to preserve good common-mode rejection.

Figure 51. Optional Trimming of the Output Offset Voltage

7.4.3 Input Bias Current Return Path

The input impedance of the INA188 is extremely high—approximately 20 GΩ. However, a path must be provided for the input bias current of both inputs. This input bias current is typically 750 pA. High input impedance means that this input bias current changes very little with varying input voltage.

Input circuitry must provide a path for this input bias current for proper operation. [Figure](#page-22-0) 52 shows various provisions for an input bias current path. Without a bias current path, the inputs float to a potential that exceeds the common-mode range of the INA188, and the input amplifiers saturate. If the differential source resistance is low, the bias current return path can be connected to one input (as shown in the thermocouple example in [Figure](#page-22-0) 52). With a higher source impedance, using two equal resistors provides a balanced input with possible advantages of a lower input offset voltage as a result of bias current and better high-frequency common-mode rejection.

Figure 52. Providing an Input Common-Mode Current Path

7.4.4 Driving the Reference Pin

The output voltage of the INA188 is developed with respect to the voltage on the reference pin. Often, the reference pin (pin 5) is connected to the low-impedance system ground in dual-supply operation. In single-supply operation, offsetting the output signal to a precise mid-supply level (for example, 2.5 V in a 5-V supply environment) can be useful. To accomplish this, a voltage source can be tied to the REF pin to level-shift the output so that the INA188 can drive a single-supply analog-to-digital converter (ADC).

For best performance, keep the source impedance to the REF pin below 5 Ω. As illustrated in the *[Functional](#page-16-2) Block [Diagram](#page-16-2)* section, the reference pin is internally connected to a 20-kΩ resistor. Additional impedance at the REF pin adds to this 20-kΩ resistor. The imbalance in the resistor ratios results in degraded common-mode rejection ratio (CMRR).

[Figure](#page-23-0) 53 shows two different methods of driving the reference pin with low impedance. The [OPA330](http://focus.ti.com/docs/prod/folders/print/opa330.html) is a lowpower, chopper-stabilized amplifier, and therefore offers excellent stability over temperature. The OPA330 is available in a space-saving SC70 and an even smaller chip-scale package. The [REF3225](http://focus.ti.com/docs/prod/folders/print/ref3225.html) is a precision reference in a small SOT23-6 package.

a) Level shifting using the OPA330 as a low-impedance buffer. b) Level shifting using the low-impedance output of the REF3225.

Figure 53. Options for Low-Impedance Level Shifting

7.4.5 Error Sources Example

Most modern signal-conditioning systems calibrate errors at room temperature. However, calibration of errors that result from a change in temperature is normally difficult and costly. Therefore, minimizing these errors is important and can be done by choosing high-precision components (such as the INA188 that has improved specifications in critical areas that impact the precision of the overall system). [Figure](#page-24-0) 54 shows an example application.

Figure 54. Example Application with G = 10 V/V and a 1-V Differential Voltage

Resistor-adjustable INAs such as the INA188 show the lowest gain error in $G = 1$ because of the inherently wellmatched drift of the internal resistors of the differential amplifier. At gains greater than 1 (for instance, $G = 10$ V/V or G = 100 V/V) the gain error becomes a significant error source because of the contribution of the resistor drift of the 25-kΩ feedback resistors in conjunction with the external gain resistor. Except for very high-gain applications, gain drift is by far the largest error contributor compared to other drift errors, such as offset drift. The INA188 offers the lowest gain error over temperature in the marketplace for both $G > 1$ and $G = 1$ (no external gain resistor). [Table](#page-25-0) 3 summarizes the major error sources in common INA applications and compares the two cases of G = 1 (no external resistor) and G = 10 (5.49-k Ω external resistor). As explained in [Table](#page-25-0) 3, although the static errors (absolute accuracy errors) in $G = 1$ are almost twice as great as compared to $G = 10$, there are much fewer drift errors because of the much lower gain error drift. In most applications, these static errors can readily be removed during calibration in production. All calculations refer the error to the input for easy comparison and system evaluation.

Total error (ppm) Total error = sum of all error sources 3034 1056

Table 3. Error Calculation

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The INA188 measures a small differential voltage with a high common-mode voltage developed between the noninverting and inverting input. The low offset drift in conjunction with no 1/f noise makes the INA188 suitable for a wide range of applications. The ability to set the reference pin to adjust the functionality of the output signal offers additional flexibility that is practical for multiple configurations.

8.2 Typical Application

[Figure](#page-26-3) 55 shows the basic connections required for operating the INA188. Applications with noisy or highimpedance power supplies may require decoupling capacitors close to the device pins. The output is referred to the output reference (REF) pin that is normally grounded. The reference pin must be a low-impedance connection to assure good common-mode rejection.

Figure 55. PLC Input (±10 V, 4 mA to 20 mA)

8.2.1 Design Requirements

For this application, the design requirements are:

- 4-mA to 20-mA input with less than 20-Ω burden
- $±20$ -mA input with less than 20- $Ω$ burden
- ±10-V input with impedance of approximately 100 kΩ
- Maximum 4-mA to 20-mA or \pm 20mA burden voltage equal to \pm 0.4 V
- Output range within 0 V to 5 V

Typical Application (continued)

8.2.2 Detailed Design Procedure

The following steps must be applied for proper device functionality:

- For a 4-mA to 20-mA input, the maximum burden of 0.4 V must have a burden resistor equal to 0.4 / 0.02 = 20 Ω.
- To center the output within the 0-V to 5-V range, V_{REF} must equal 2.5 V.
- To keep the ±20-mA input linear within 0 V to 5 V, the gain resistor (R_G) must be 12.4 kΩ.
- To keep the ±10-V input within the 0-V to 5-V range, attenuation must be greater than 0.05.
- A 100-kΩ resistor in series with a 4.87-kΩ resistor provides 0.0466 attenuation of ±10 V, well within the ±2.5-V linear limits.

8.2.3 Application Curve

Figure 56. Plot of PLC Input Transfer Function

9 Power Supply Recommendations

The minimum power-supply voltage for the INA188 is ± 2 V and the maximum power-supply voltage is ± 18 V. This minimum and maximum range covers a wide range of power supplies. However, for optimum performance, $±15$ V is recommended. A 0.1-µF bypass capacitor is recommended to be added at the input to compensate for the layout and power-supply source impedance.

10 Layout

10.1 Layout Guidelines

Attention to good layout practices is always recommended. For best operational performance of the device, use good printed circuit board (PCB) layout practices, including:

- Care must be taken to ensure that both input paths are well-matched for source impedance and capacitance to avoid converting common-mode signals into differential signals. In addition, parasitic capacitance at the gain-setting pins can also affect CMRR over frequency. For example, in applications that implement gain switching using switches or PhotoMOS® relays to change the value of R_G, select the component so that the switch capacitance is as small as possible.
- Noise can propagate into analog circuitry through the power pins of the circuit as a whole and of the device itself. Bypass capacitors are used to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
	- Connect low-ESR, 0.1-μF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for singlesupply applications.
- Separate grounding for analog and digital portions of the circuitry is one of the simplest and most effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically separate digital and analog grounds, paying attention to the flow of the ground current. For more detailed information, see [SLOA089](http://www.ti.com/lit/pdf/SLOA089), *Circuit Board Layout Techniques*.
- In order to reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If these traces cannot be kept separate, crossing the sensitive trace perpendicular is much better than in parallel with the noisy trace.
- Place the external components as close to the device as possible. As illustrated in [Figure](#page-29-1) 57, keeping R_G close to the pins minimizes parasitic capacitance.
- Keep the traces as short as possible.

10.2 Layout Example

Figure 57. PCB Layout Example

11 Device and Documentation Support

11.1 Device Support

11.1.1 Development Support

Table 4. Table 1. Design Kits and Evaluation Modules

Table 5. Table 2. Development Tools

11.2 Documentation Support

11.2.1 Related Documentation

OPA188 Data Sheet, [SBOS642](http://www.ti.com/lit/pdf/SBOS642)

OPA330 Data Sheet, [SBOS432](http://www.ti.com/lit/pdf/SBOS432)

REF3225 Data Sheet, [SBVS058](http://www.ti.com/lit/pdf/SBVS058)

Circuit Board Layout Techniques, [SLOA089](http://www.ti.com/lit/pdf/SLOA089)

11.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms](http://www.ti.com/corp/docs/legal/termsofuse.shtml) of [Use.](http://www.ti.com/corp/docs/legal/termsofuse.shtml)

TI E2E™ Online [Community](http://e2e.ti.com) *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design [Support](http://support.ti.com/) *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.4 Trademarks

E2E is a trademark of Texas Instruments. Bluetooth is a registered trademark of Bluetooth SIG, Inc. PhotoMOS is a registered trademark of Panasonic Electric Works Europe AG. All other trademarks are the property of their respective owners.

11.5 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.6 Glossary

[SLYZ022](http://www.ti.com/lit/pdf/SLYZ022) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check<http://www.ti.com/productcontent>for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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MECHANICAL DATA

 $C.$ SON (Small Outline No-Lead) package configuration.

 $\overline{\bigtriangleup}$ The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.

E. Package complies to JEDEC MO-229 variation WGGB.

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

NOTE: All linear dimensions are in millimeters

NOTES: All linear dimensions are in millimeters. А.

- This drawing is subject to change without notice. **B.**
- Publication IPC-7351 is recommended for alternate designs. C.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>.
- E. Laser cutting apertures with electropolish and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for solder mask tolerances and vias tenting recommendations for vias placed in the thermal pad.

 $D (R-PDSO-G8)$

PLASTIC SMALL OUTLINE

NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- 6 Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations. E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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